



N 沟道增强型场效应晶体管

N-CHANNEL MOSFET

FHP3710C

主要参数 MAIN CHARACTERISTICS

ID	57A
VDSS	100 V
Rdson-typ (@Vgs=10V)	18mΩ
Qg-typ	130nC

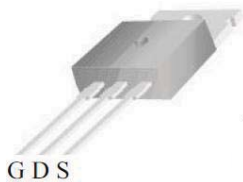
用途 APPLICATIONS

逆变电源	Power management for inverter systems
DC-DC转换器和功率开关	DC-DC converter and switch mode power supplies

产品特性 FEATURES

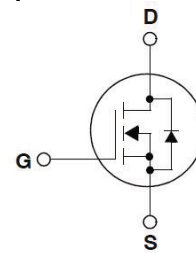
低栅极电荷	Low gate charge
低 Crss (典型值 72pF)	Low Crss (typical 72pF)
开关速度快	Fast switching
100%经过雪崩测试	100% avalanche tested
高抗 dv/dt 能力	Improved dv/dt capability
RoHS 产品	RoHS product

封装形式 Package



TO-220
FHP series

等效电路 Equivalent Circuit



绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
		FHP3710C	
最高漏极-源极直流电压 Drain-Source Voltage	V _{DS}	100	V
连续漏极电流* Drain Current -continuous *	I _D (T _C =25°C)	57	A
	I _D (T _C =100°C)	40	A
最大脉冲漏极电流 (注 1) Drain Current - pulse (note 1)	I _{DM}	228	A
最高栅源电压 Gate-Source Voltage	V _{GS}	±20	V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	E _{AS}	480	mJ
雪崩电流 (注 1) Avalanche Current (note 1)	I _{AR}	28	A
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	E _{AR}	20	mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	5.0	V/ns
耗散功率 Power Dissipation	P _D (T _C =25°C)	200	W
	-Derate above 25°C	1.3	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T _J , T _{STG}	-55~+175	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T _L	300	°C

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
关态特性 Off –Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	100	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	ΔBV _{DSS} /ΔT _J	I _D =250μA, referenced to 25°C	-	0.01	-	V/°C
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V, T _C =25°C	-	-	1	μA
		V _{DS} =80V, T _C =125°C	-	-	10	μA
栅极体漏电流 Gate-body leakage current	I _{GSS (F/R)}	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =250μA	2.0	3.0	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V , I _D =28A	-	18	23	mΩ
正向跨导 Forward Transconductance	g _{fs}	V _{DS} = 20V, I _D =28A (note 4)	-	60	-	S
动态特性 Dynamic Characteristics						
栅电阻 Gate Resistance	R _g	f=1.0MHz, V _{DS} OPEN	-	1.3	-	Ω
输入电容 Input capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHz	-	3130	-	pF
输出电容 Output capacitance	C _{oss}		-	410	-	
反向传输电容 Reverse transfer capacitance	C _{rss}		-	72	-	
开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	t _{d(on)}	V _{DS} =50V, I _D =28A, R _G =2.5Ω V _{GS} =10V (note 4, 5)	-	12	-	ns
上升时间 Turn-On rise time	t _r		-	58	-	ns
延迟时间 Turn-Off delay time	t _{d(off)}		-	45	-	ns
下降时间 Turn-Off Fall time	t _f		-	47	-	ns
栅极电荷总量 Total Gate Charge	Q _g	V _{DS} =80V , I _D =28A , V _{GS} =10V (note 4, 5)	-	-	130	nC
栅—源电荷 Gate-Source charge	Q _{gs}		-	-	26	nC
栅—漏电荷 Gate-Drain charge	Q _{gd}		-	-	43	nC
漏—源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current		I _S	-	-	60	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		I _{SM}	-	-	240	A
正向压降 Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =28A	-	0.82	1.3	V
反向恢复时间 Reverse recovery time	t _{rr}	V _{GS} =0V, I _S =28A ,dI _F /dt=100A/μs (note 4)	-	140	-	ns
反向恢复电荷 Reverse recovery charge	Q _{rr}		-	670	-	nC

热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	最大值 Max	单位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	Rth(j-c)	0.75	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	Rth(j-A)	62.5	°C/W

注释:

- 1: 脉冲宽度由最高结温限制
- 2: L=1mH, IAS=28A, VDD=48V, RG=25 Ω, 起始结温 TJ=25°C
- 3: ISD ≤57A, di/dt ≤300A/μs, VDD≤BVDS, 起始结温 TJ=25°C
- 4: 脉冲测试: 脉冲宽度 ≤300μs, 占空比≤2%
- 5: 基本与工作温度无关

Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: L=1mH, IAS=28A, VDD=48V, RG=25 Ω, Starting TJ=25°C
- 3: ISD ≤57A, di/dt ≤300A/μs, VDD≤BVDS, Starting TJ=25°C
- 4: Pulse Test: Pulse Width ≤300μs, Duty Cycle≤2%
- 5: Essentially independent of operating temperatur

Typical Characteristics

典型特性曲线

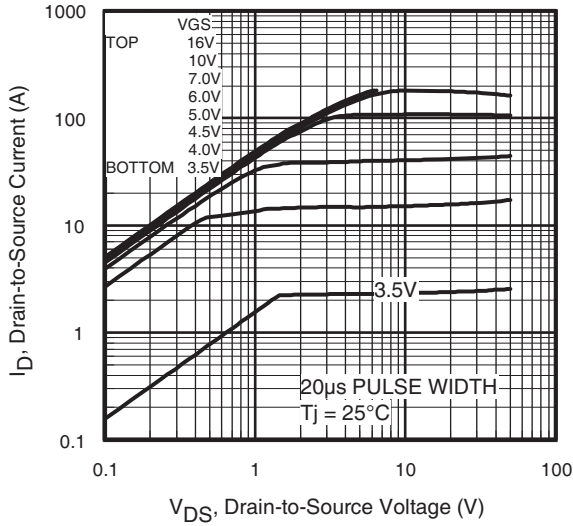


Fig 1. Typical Output Characteristics

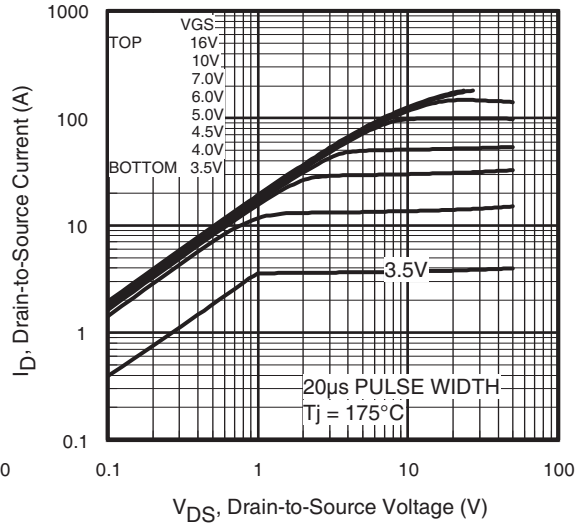


Fig 2. Typical Output Characteristics

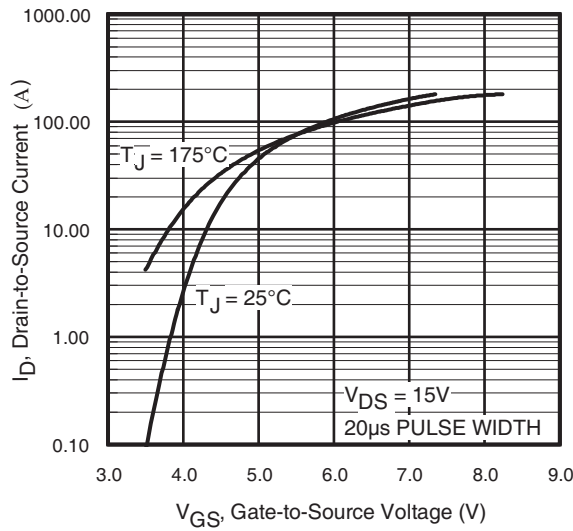


Fig 3. Typical Transfer Characteristics

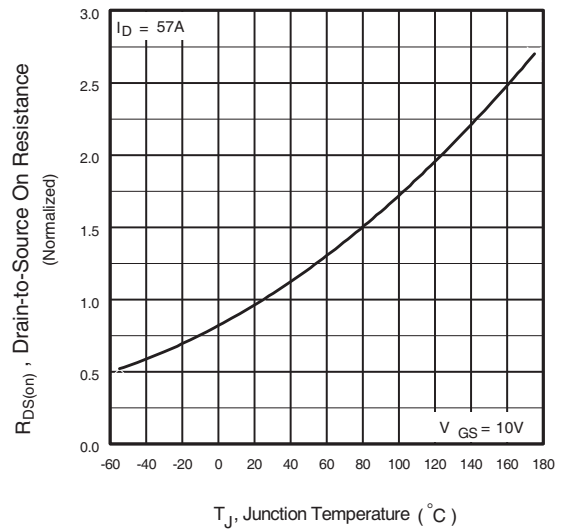


Fig 4. Normalized On-Resistance Vs. Temperature

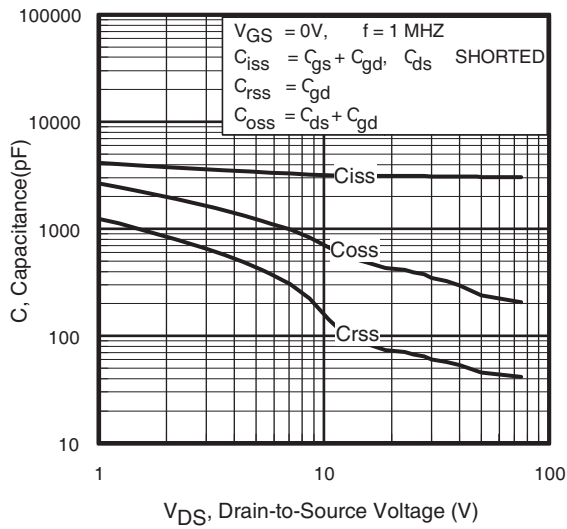


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

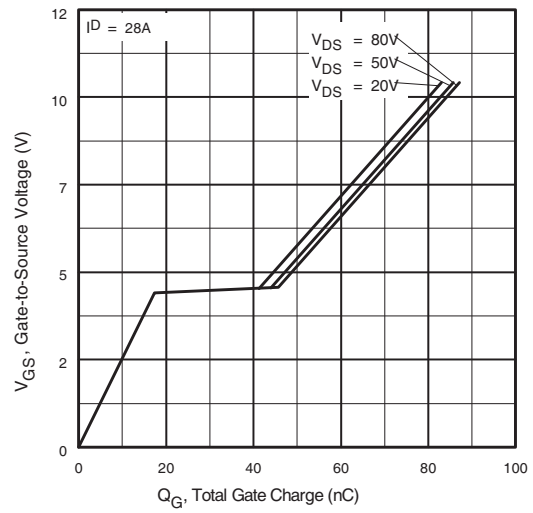


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

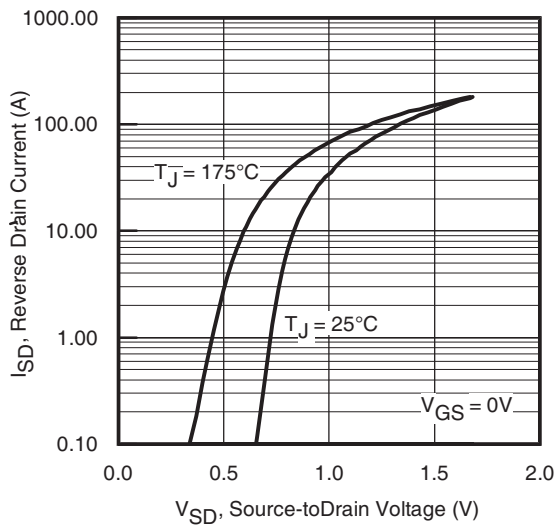


Fig 7. Typical Source-Drain Diode Forward Voltage

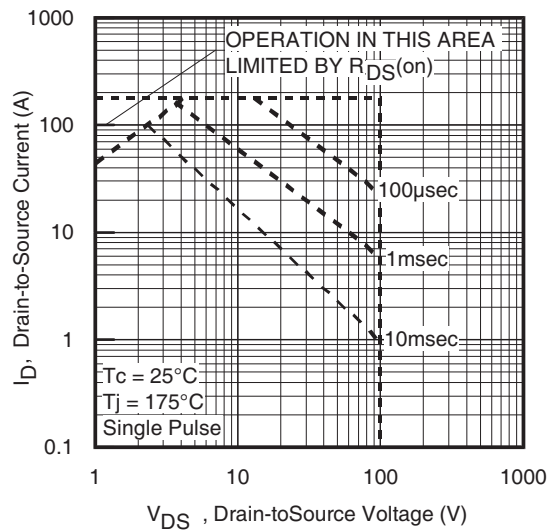


Fig 8. Maximum Safe Operating Area

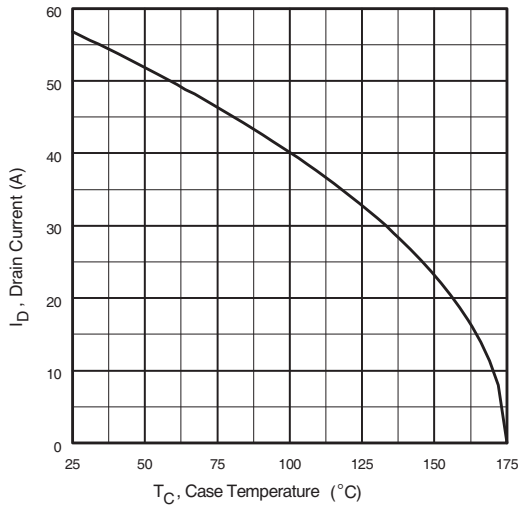


Fig 9. Maximum Drain Current Vs. Case Temperature

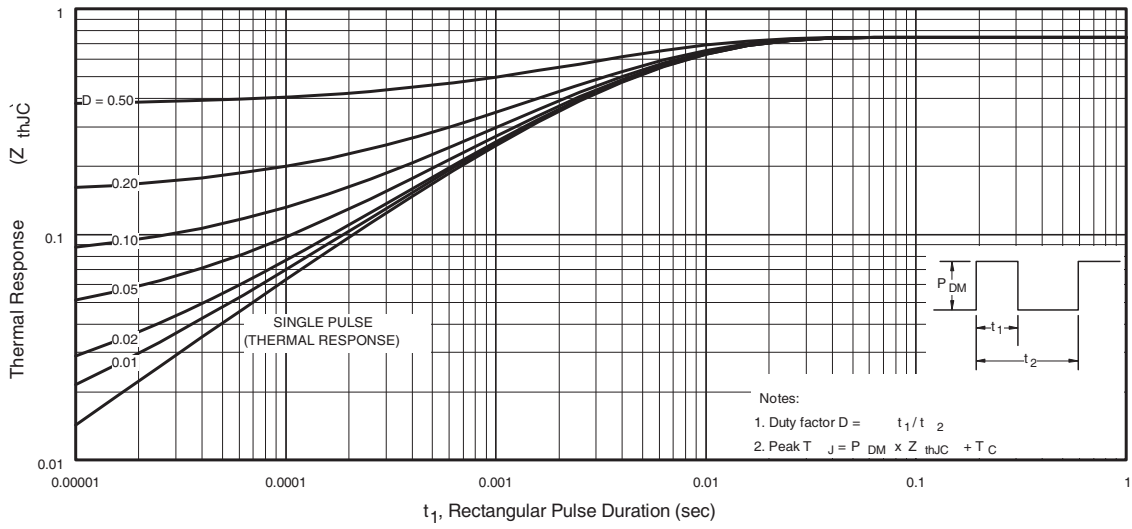


Fig 10. Maximum Effective Transient Thermal Impedance, Junction-to-Case

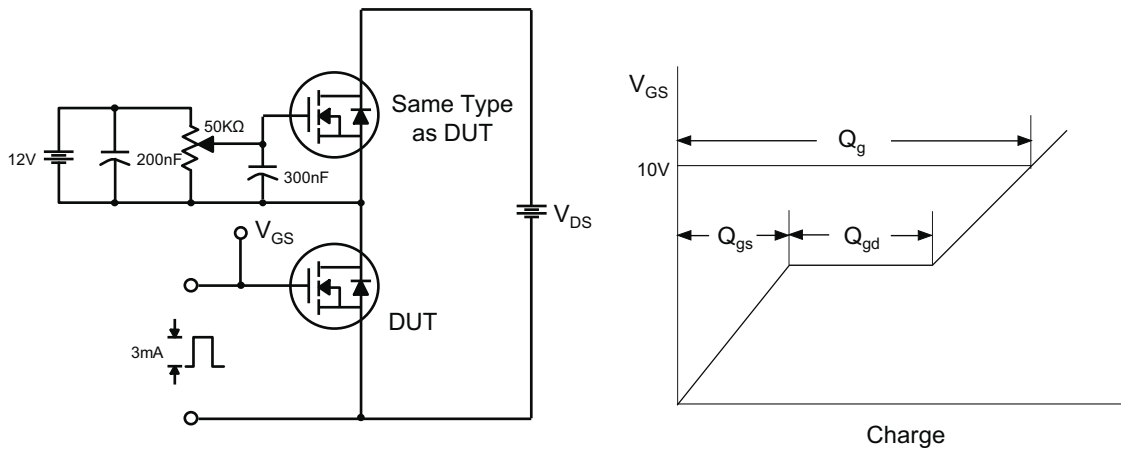


Fig 11. Gate Charge Test Circuit & Waveform

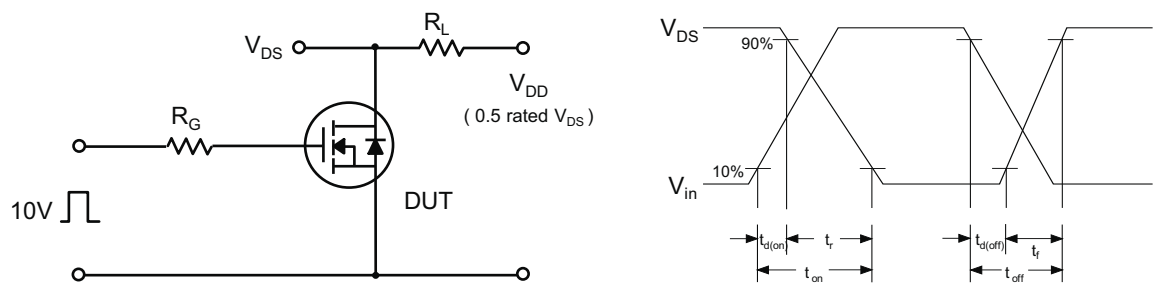


Fig 12. Resistive Switching Test Circuit & Waveforms

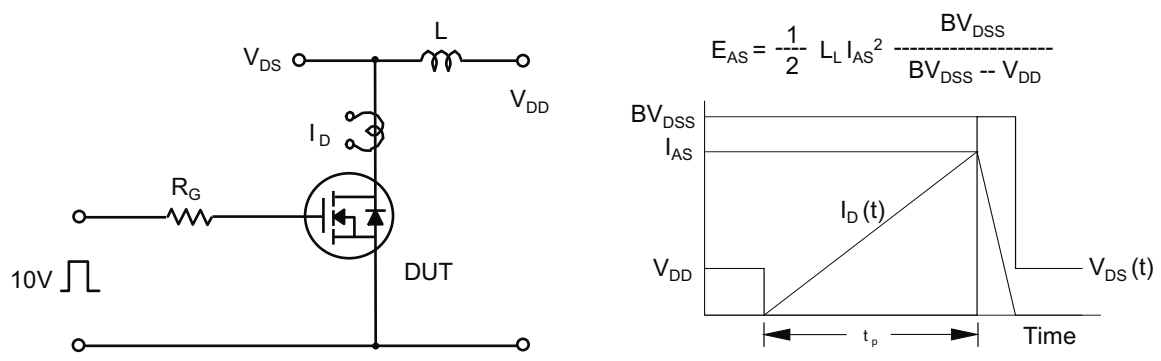


Fig 13. Unclamped Inductive Switching Test Circuit & Waveforms

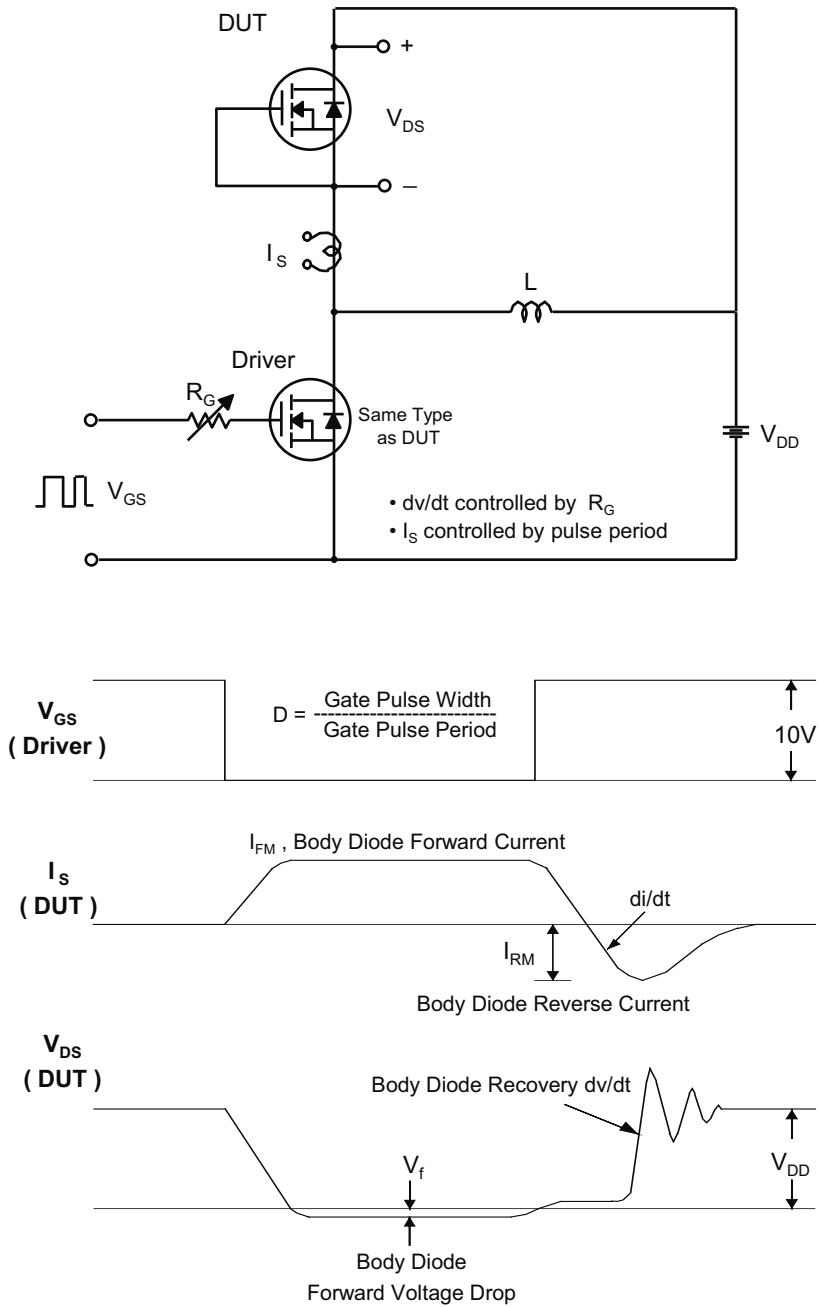
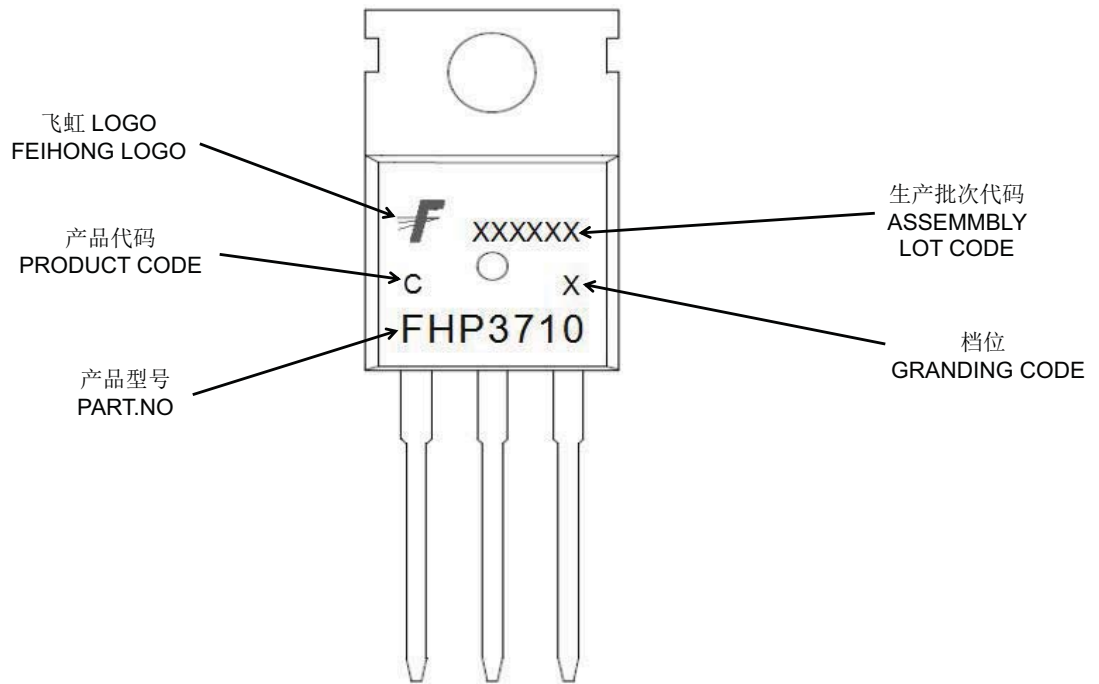


Fig 14. Peak Diode Recovery dv/dt Test Circuit & Waveforms

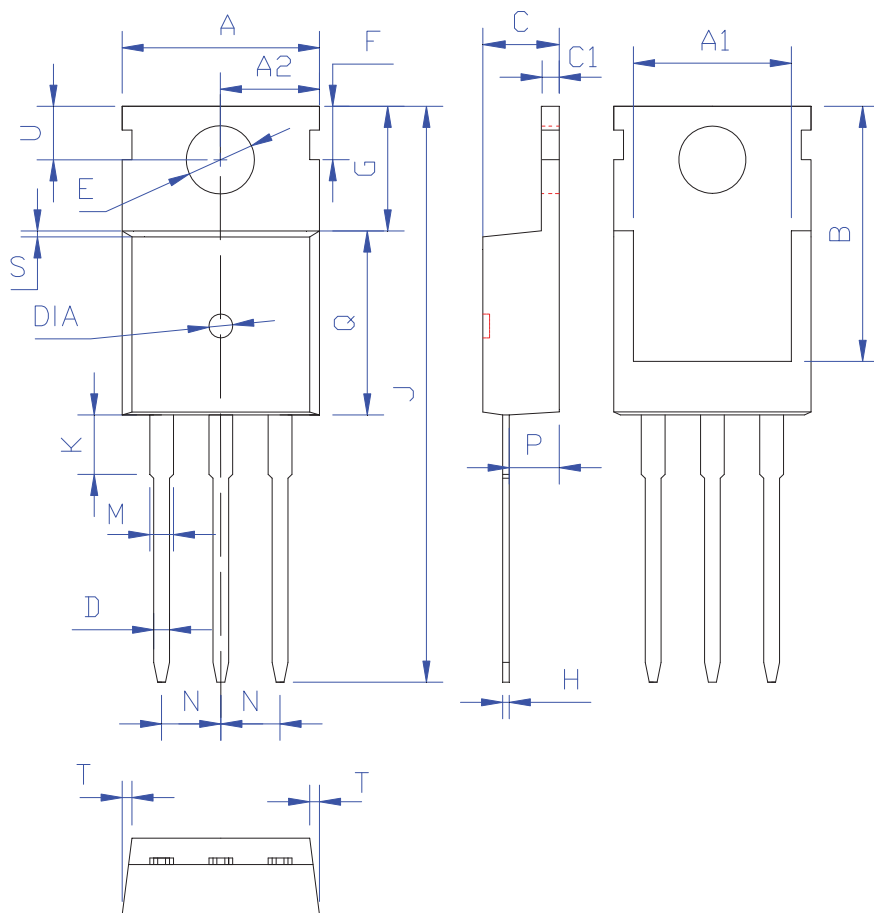
印记 Marking:



外形尺寸:

Package Dimension:

TO-220



DIM	MILLIMETERS
A	10.00 ± 0.30
A1	8.00 ± 0.30
A2	5.00 ± 0.30
B	13.20 ± 0.40
C	4.50 ± 0.20
C1	1.30 ± 0.20
D	0.80 ± 0.20
E	3.60 ± 0.20
F	3.00 ± 0.30
G	6.60 ± 0.40
H	0.50 ± 0.20
J	28.88 ± 0.50
K	3.00 ± 0.30
M	1.30 ± 0.30
N	Typical 2.54
P	2.40 ± 0.40
Q	9.20 ± 0.40
S	0.25 ± 0.15
T	0.25 ± 0.15
U	2.80 ± 0.30
DIA	宽 1.50 ± 0.10 深 0.50 MAX

(Unit: mm)

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